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## BJT and BJT Circuit

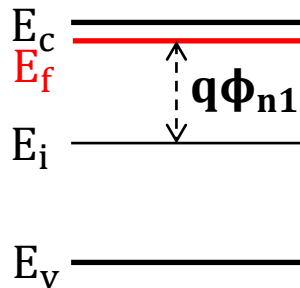
Ve311 Electronic Circuits (Fall 2020)

Dr. Chang-Ching Tu

# BJT (Before Contact)

## Emitter

n-type

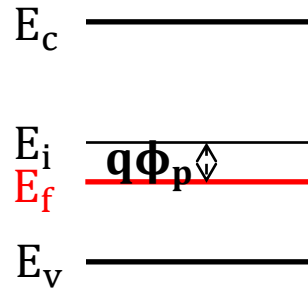


$$n \cong N_{d1} = n_i e^{\frac{q\phi_{n1}}{kT}}$$

$$p \cong \frac{n_i^2}{N_{d1}} = n_i e^{\frac{-q\phi_{n1}}{kT}}$$

## Base

p-type

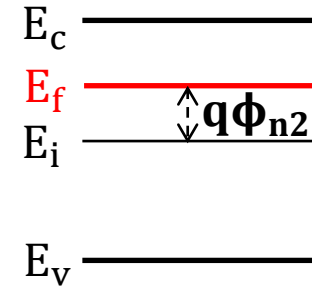


$$p \cong N_a = n_i e^{\frac{q\phi_p}{kT}}$$

$$n \cong \frac{n_i^2}{N_a} = n_i e^{\frac{-q\phi_p}{kT}}$$

## Collector

n-type

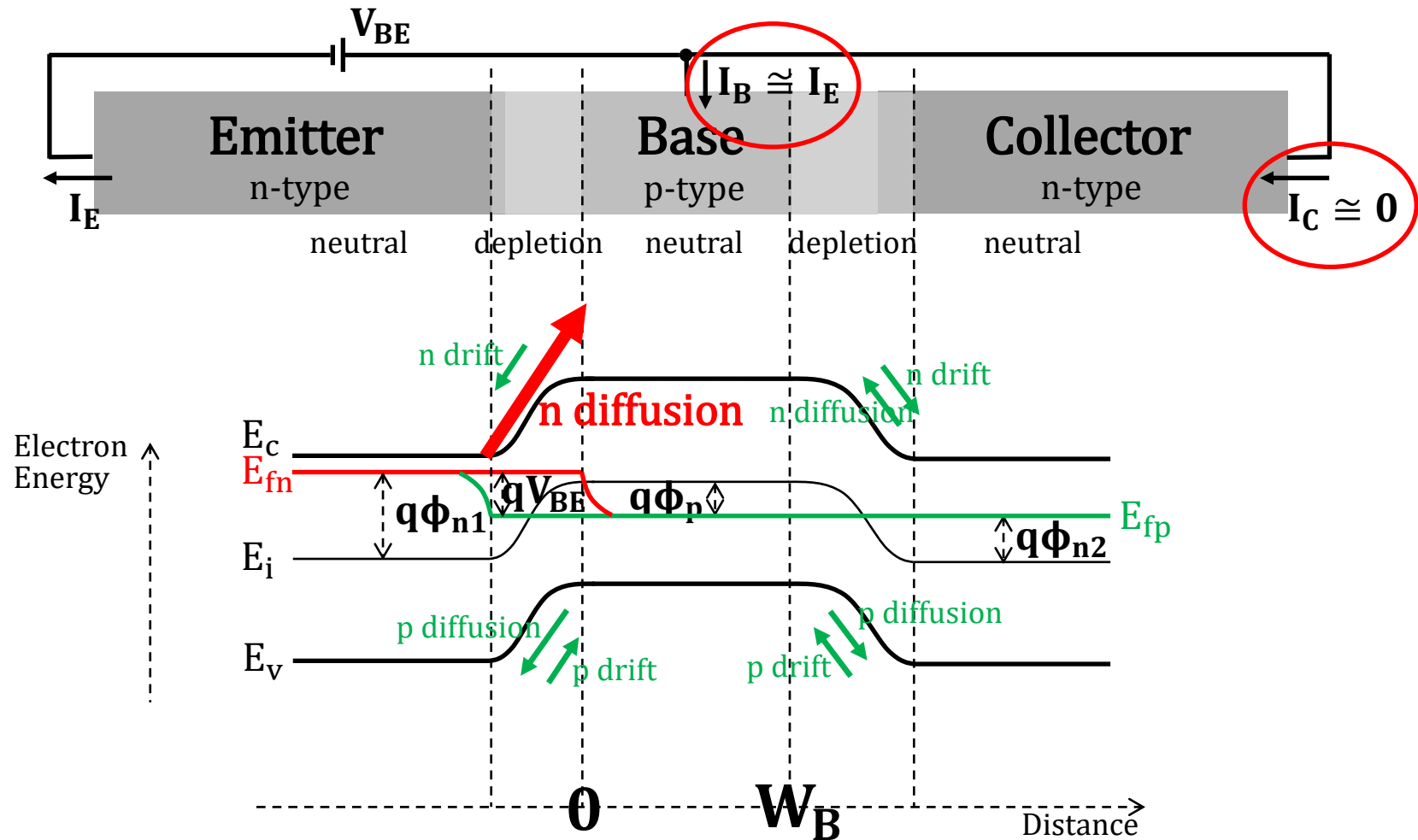


$$n \cong N_{d2} = n_i e^{\frac{q\phi_{n2}}{kT}}$$

$$p \cong \frac{n_i^2}{N_{d2}} = n_i e^{\frac{-q\phi_{n2}}{kT}}$$

$$N_{d1} \gg N_a$$

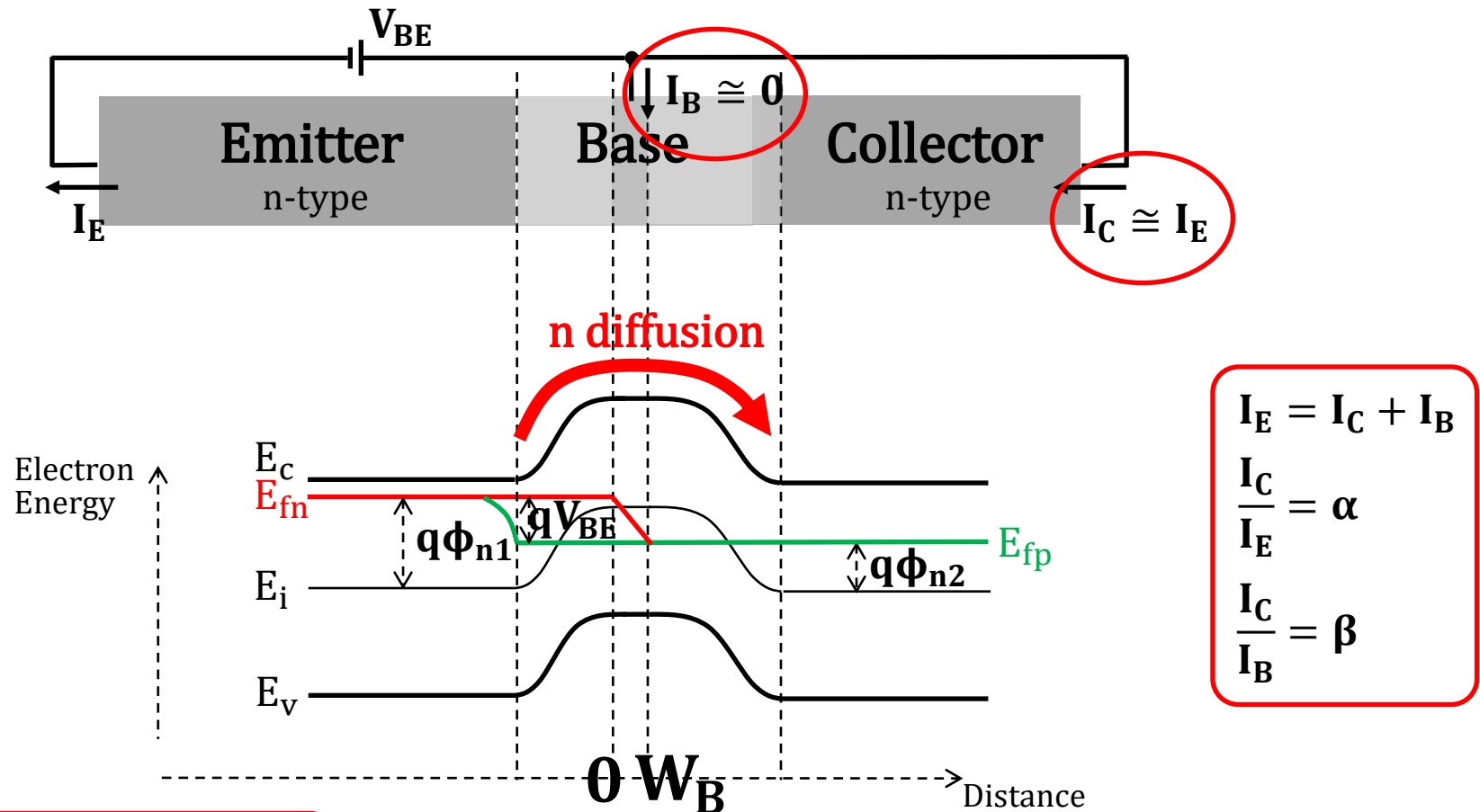
$$V_{BE} > 0 \text{ and } V_{CB} = 0 \text{ (} W_B \text{ long)}$$



$$N_{d1} \gg N_a$$

The n (electron) diffusion is much larger than the p (hole) diffusion at the Base-Emitter junction.

$V_{BE} > 0$  and  $V_{CB} = 0$  ( $W_B$  very short)



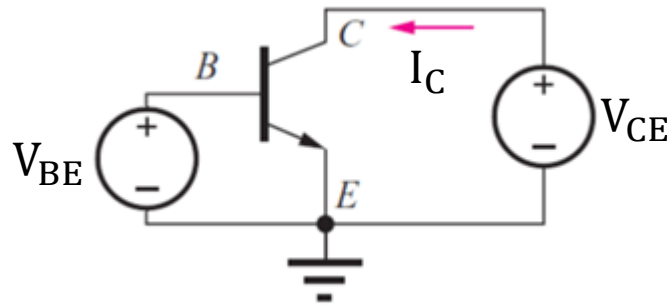
$$N_{d1} \gg N_a$$

The n (electron) diffusion is much larger than the p (hole) diffusion at the Base-Emitter junction.

**$W_B$  very short**

Nearly all the n (electron) diffusion from the Base-Emitter junction pass through the Base, enter into the depletion region of the Base-Collector junction, and are swept to the Collector side by the built-in electric field.

# Summary



$V_{CE} \geq V_{BE}$   
 $\Rightarrow$  Forward – Active

**Ideal case**

$$I_C = I_S \left( e^{\frac{qV_{BE}}{kT}} - 1 \right)$$

$$\alpha = \frac{I_C}{I_E} \cong 1$$

$$\beta = \frac{I_C}{I_B} = \frac{\alpha}{1 - \alpha}$$



$$I_C = I_S \left( e^{\frac{qV_{BE}}{kT}} - 1 \right)$$

$$\alpha = \frac{I_C}{I_E} = 1$$

$$\beta = \frac{I_C}{I_B} = \infty$$

$I_S$  is a constant in the spice model.

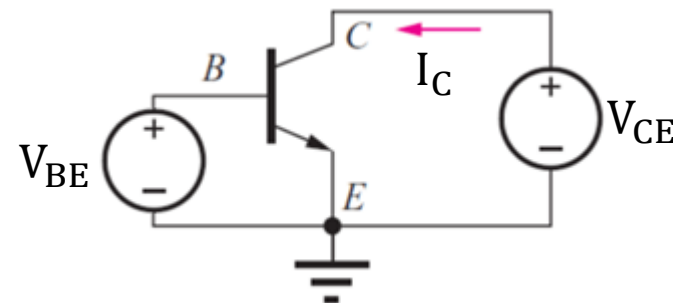
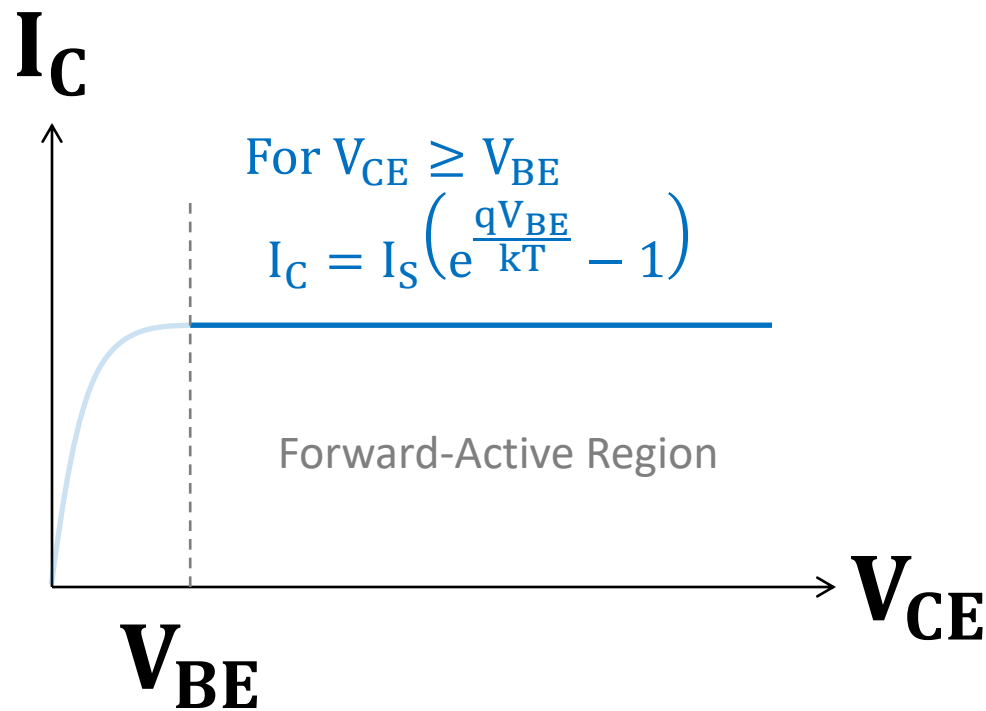
$I_C$  vs  $V_{CE}$  and  $I_C$  vs  $V_{BE}$   
in Forward-Active Region

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# $I_C$ vs $V_{CE}$ (not considering Early Effect)

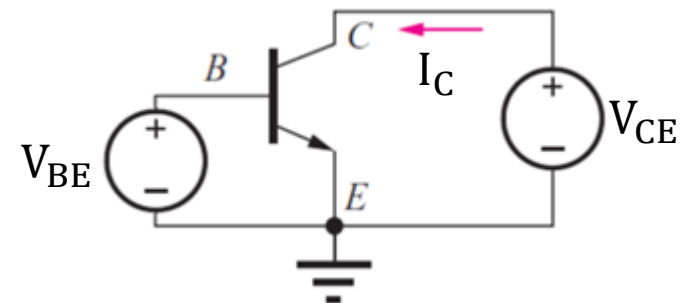
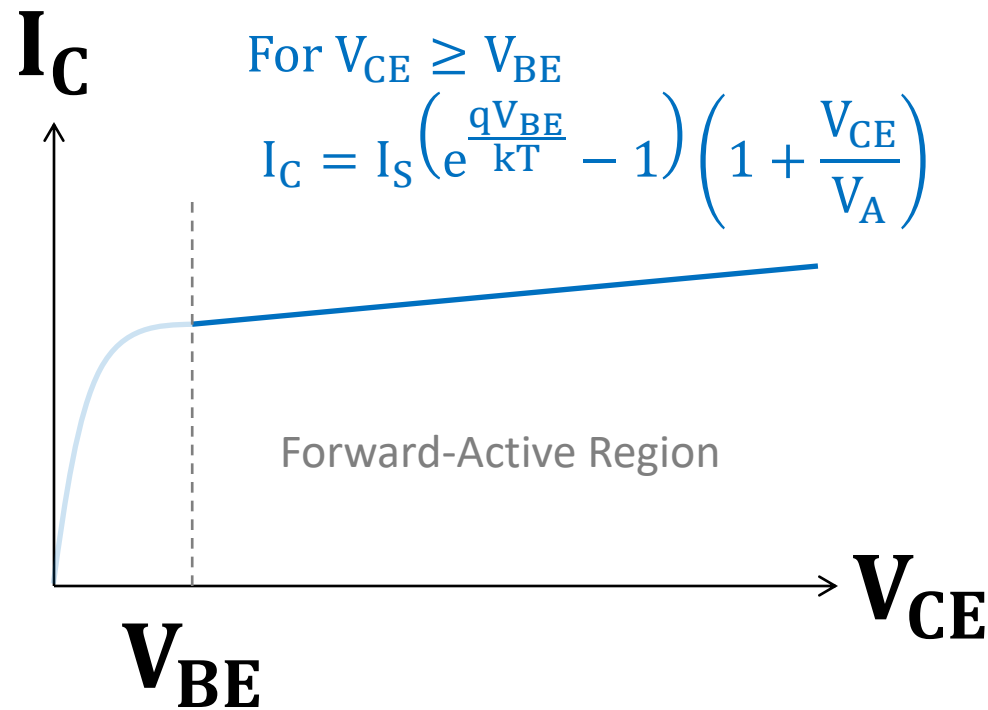
7

At given  $V_{BE}$ , DC sweep  $V_{CE}$



# $I_C$ vs $V_{CE}$ (considering Early Effect)

At given  $V_{BE}$ , DC sweep  $V_{CE}$



$V_A$  is a constant in the spice model.

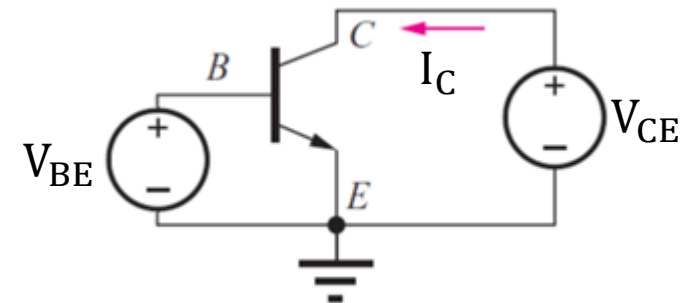
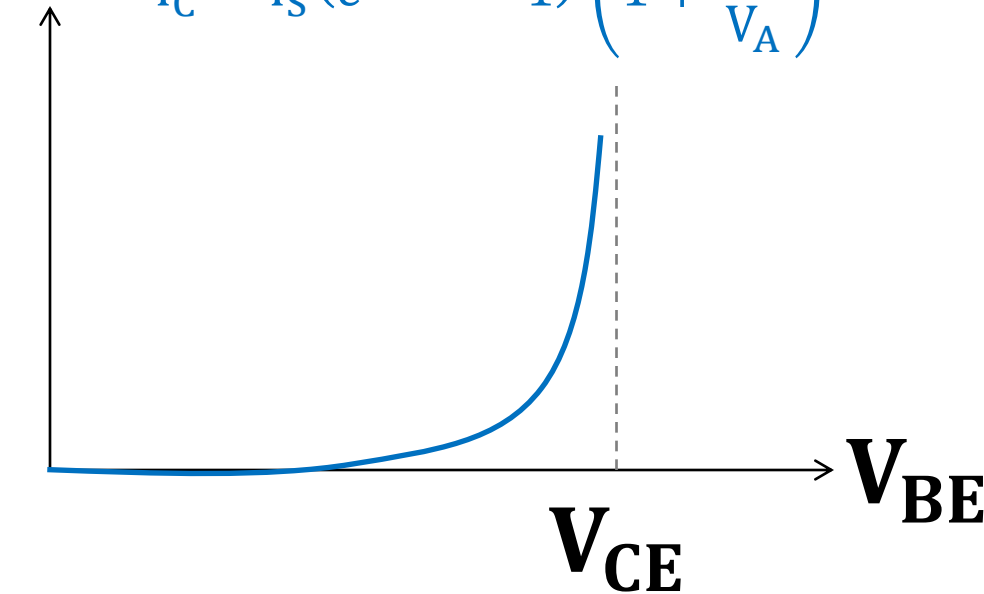


# $I_C$ vs $V_{BE}$

At given  $V_{CE}$ , DC sweep  $V_{BE}$

For  $V_{CE} \geq V_{BE}$

$$I_C = I_S \left( e^{\frac{qV_{BE}}{kT}} - 1 \right) \left( 1 + \frac{V_{CE}}{V_A} \right)$$

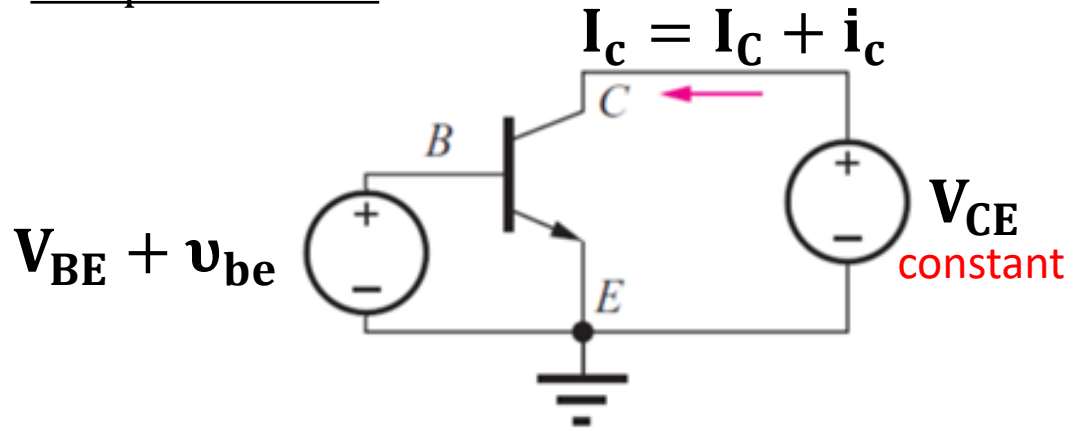


# Small-Signal Model

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# Hybrid- $\pi$ Model (how to get $g_m$ and $r_\pi$ )

Complete circuit:



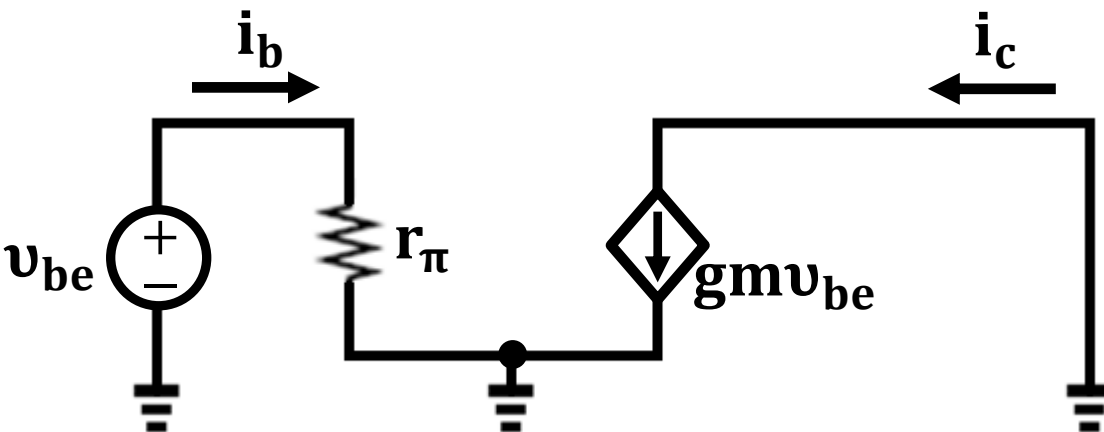
$$V_{CE} \geq V_{BE}$$

$\Rightarrow$  Forward – Active

$$I_C = I_S \left( e^{\frac{qV_{BE}}{kT}} - 1 \right) \left( 1 + \frac{V_{CE}}{V_A} \right)$$



Small-signal circuit:

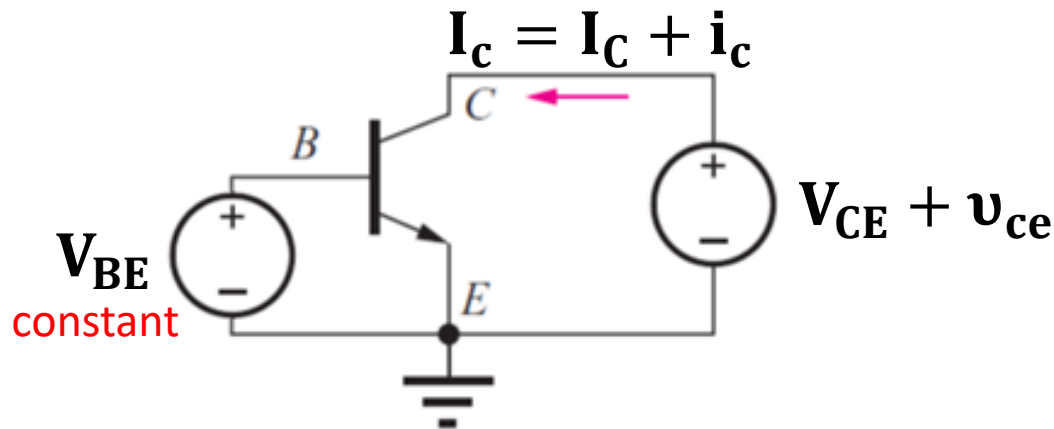


$$r_\pi = \frac{dV_{BE}}{dI_B} = \frac{1}{\frac{dI_C}{\beta dV_{BE}}} = \frac{1}{\frac{g_m}{\beta}} = \frac{\beta}{g_m}$$

$$g_m = \frac{dI_C}{dV_{BE}} \approx \frac{I_C}{kT/q}$$

# Hybrid- $\pi$ Model (how to get $r_o$ )

Complete circuit:

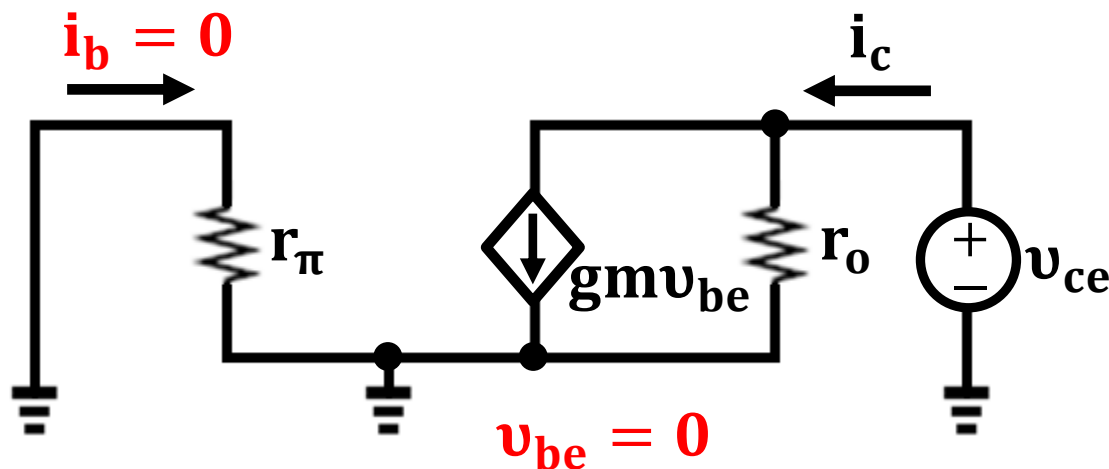


$$V_{CE} \geq V_{BE}$$

$\Rightarrow$  Forward – Active

$$I_C = I_S \left( e^{\frac{qV_{BE}}{kT}} - 1 \right) \left( 1 + \frac{V_{CE}}{V_A} \right)$$

Small-signal circuit:



$$r_\pi = \frac{1}{\frac{dI_B}{dV_{BE}}} = \frac{1}{\frac{dI_C}{\beta dV_{BE}}} = \frac{1}{\frac{gm}{\beta}} = \frac{\beta}{gm}$$

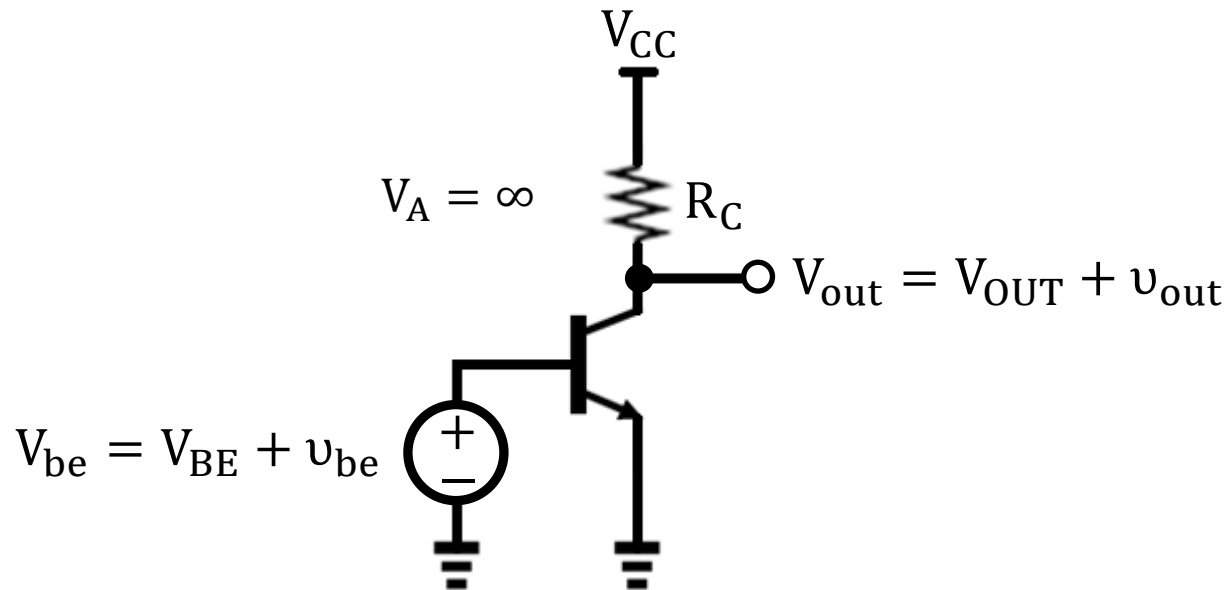
$$gm = \frac{dI_C}{dV_{BE}} \approx \frac{I_C}{kT/q}$$

$$r_o = \frac{1}{\frac{dI_C}{dV_{CE}}} \approx \frac{V_A}{I_C}$$

# Common-Emitter Amplifier

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# Common-Emitter Amplifier ( $V_A = \infty$ )

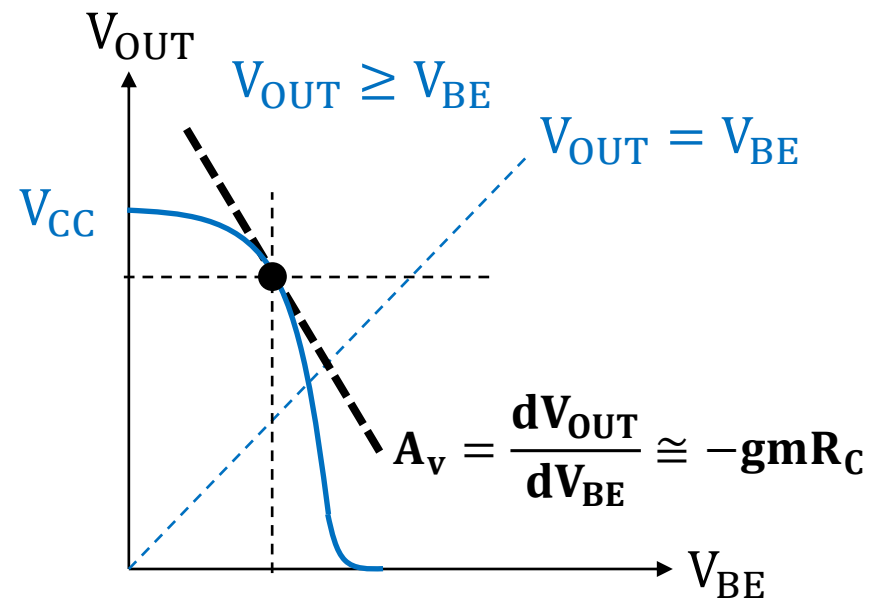


## • DC Analysis

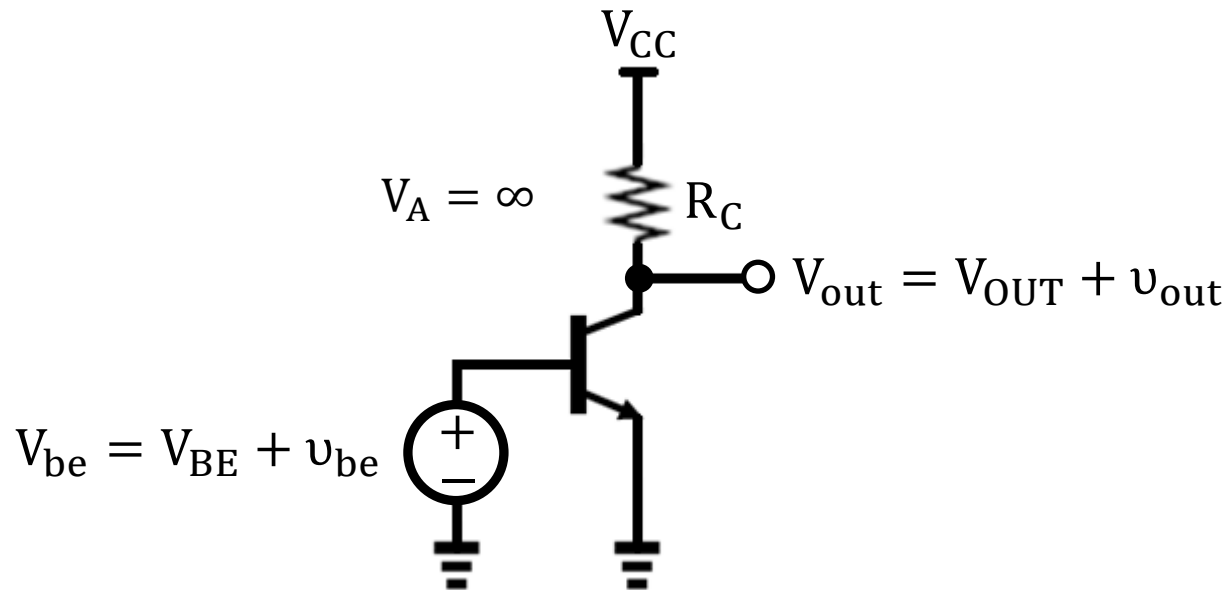
$$V_{OUT} = V_{CC} - I_C R_C$$

$$= V_{CC} - \frac{A q D_n n_i^2}{N_a W_B} \left( e^{\frac{q V_{BE}}{kT}} - 1 \right) R_C$$

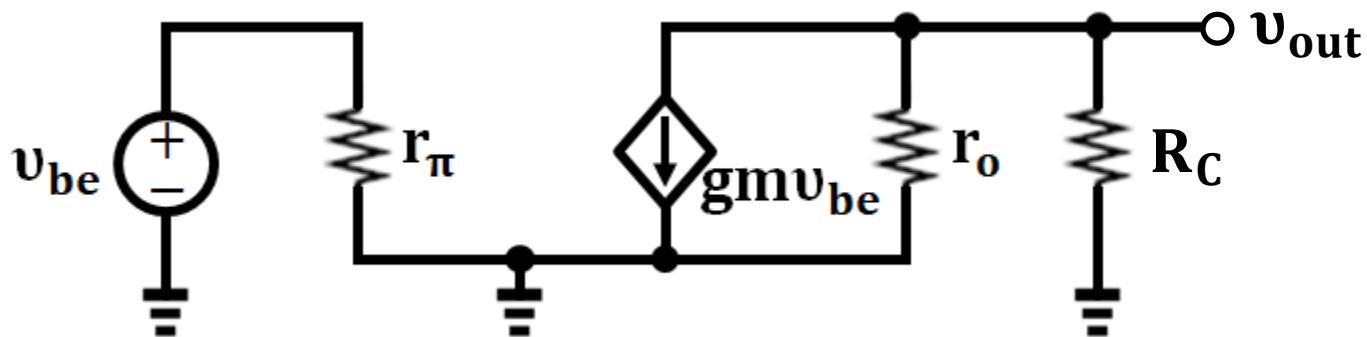
$$A_v = \frac{dV_{OUT}}{dV_{BE}} \cong -\frac{I_C}{kT/q} R_C = -g_m R_C$$



# Common-Emitter Amplifier ( $V_A = \infty$ )

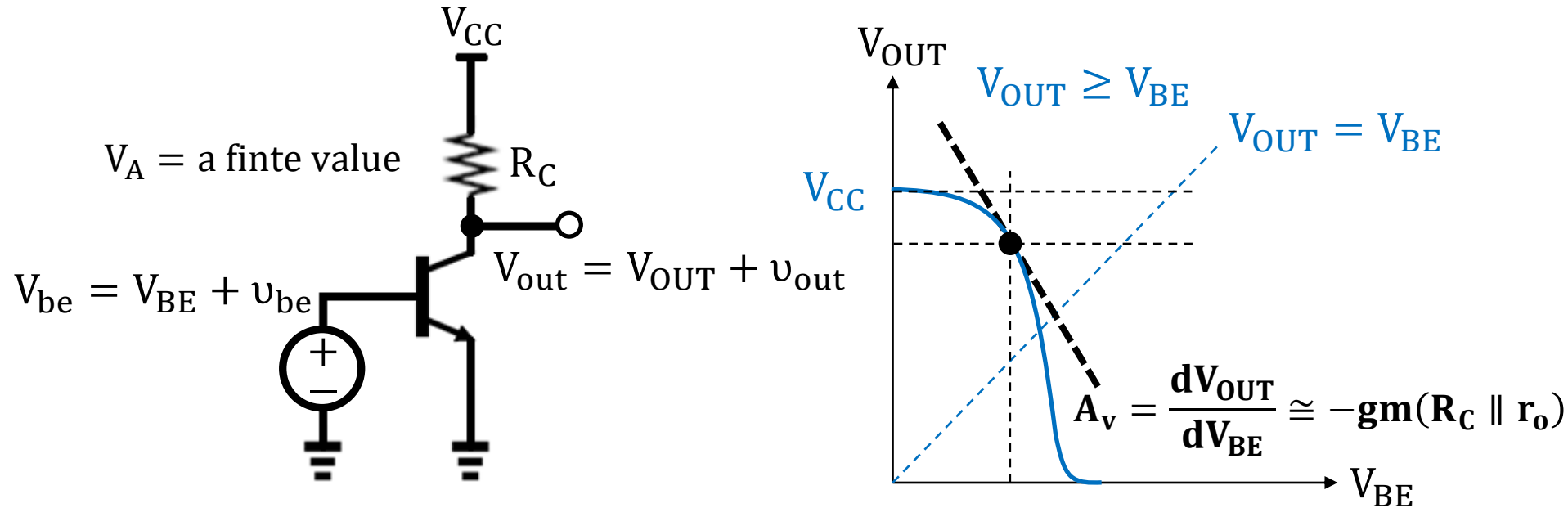


- Small-Signal Analysis



$$A_v = \frac{v_{out}}{v_{be}} = -gm(R_C \parallel r_o) = -gmR_C \quad (\text{since } r_o = \infty)$$

# Common-Emitter Amplifier ( $V_A = \text{a finite value}$ )<sup>16</sup>



## • DC Analysis

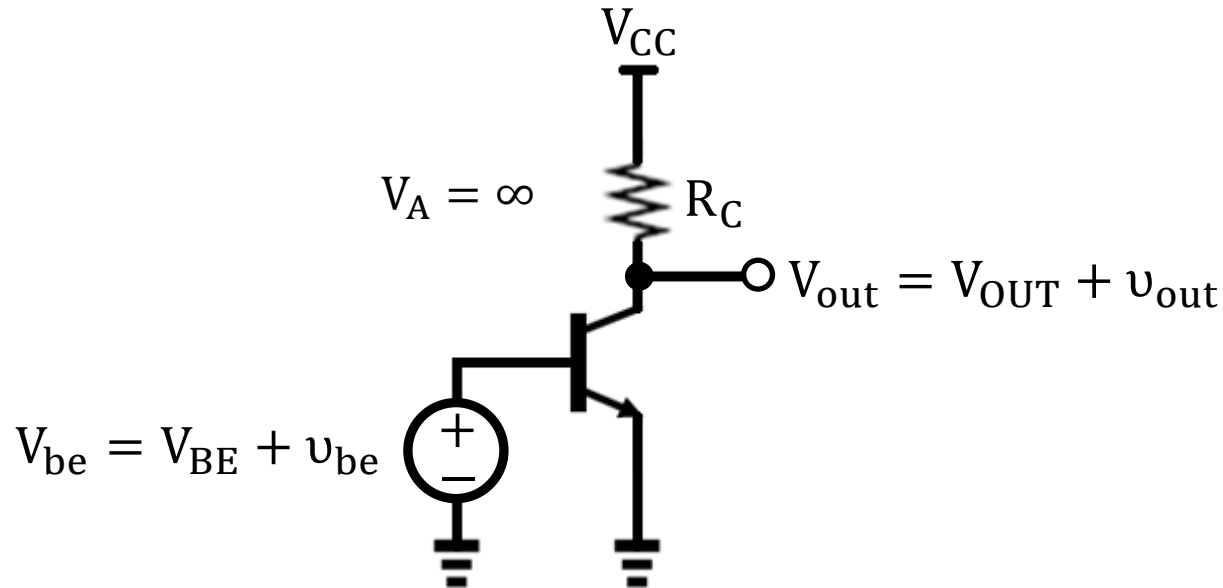
$$V_{OUT} = V_{CC} - I_C R_C = V_{CC} - I_S \left( e^{\frac{qV_{BE}}{kT}} - 1 \right) \left( 1 + \frac{V_{OUT}}{V_A} \right) R_C$$

$$\frac{dV_{OUT}}{dV_{BE}} = -\frac{q}{kT} I_S e^{\frac{qV_{BE}}{kT}} \left( 1 + \frac{V_{OUT}}{V_A} \right) R_C - I_S \left( e^{\frac{qV_{BE}}{kT}} - 1 \right) \frac{1}{V_A} \frac{dV_{OUT}}{dV_{BE}} R_C \cong -gm R_C - \frac{1}{r_o} \frac{dV_{OUT}}{dV_{BE}} R_C$$

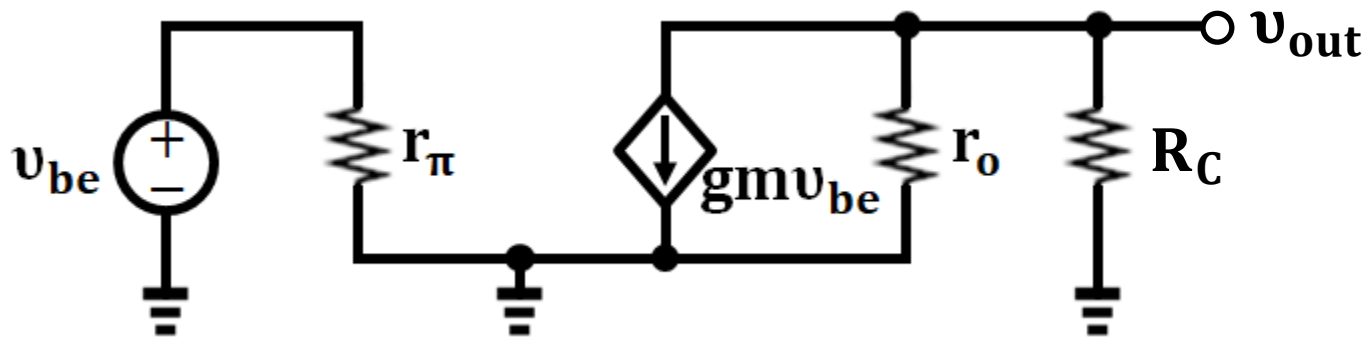
$$A_v = \frac{dV_{OUT}}{dV_{BE}} \cong -gm(R_C \parallel r_o)$$



# Common-Emitter Amplifier ( $V_A = \text{a finite value}$ )<sup>17</sup>



- Small-Signal Analysis

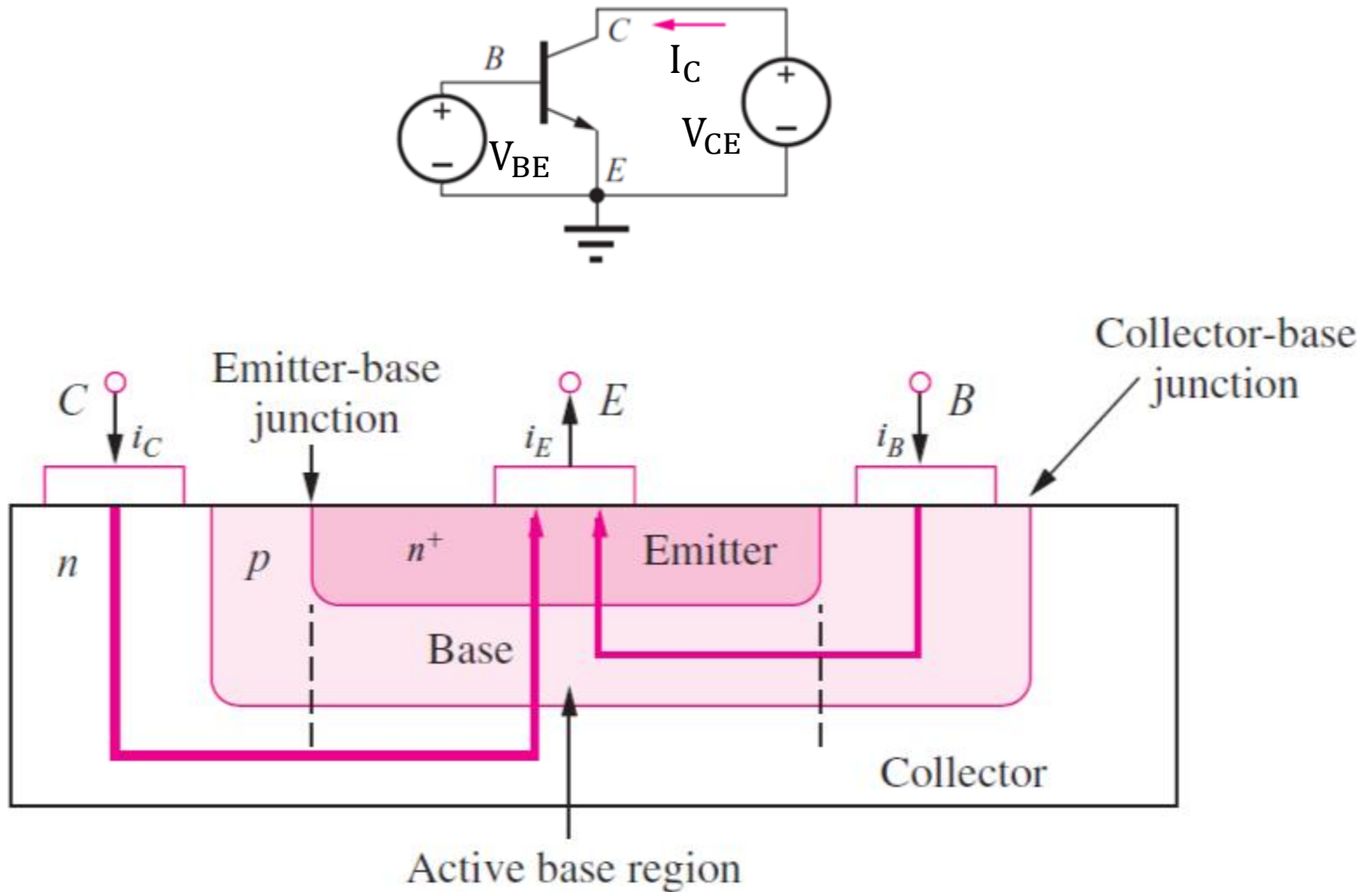


$$A_v = \frac{v_{out}}{v_{be}} = -gm(R_C \parallel r_o)$$

# BJT Structure and Pspice Model

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# npn BJT Cross Section



# npn BJT Pspice Model

.model Qbreakn NPN IS=1e-18 BF=100 VAF=100

$$I_C = \textcolor{blue}{IS} \left( e^{\frac{qV_{BE}}{kT}} - 1 \right) \left( 1 + \frac{V_{CE}}{\textcolor{blue}{VAF}} \right)$$

$$\textcolor{blue}{BF} = \frac{I_C}{I_B} \quad I_E = I_C + I_B$$

$$g_m \cong \frac{I_C}{kT/q} \quad r_\pi = \frac{\textcolor{blue}{BF}}{g_m} \quad r_o \cong \frac{\textcolor{blue}{VAF}}{I_C}$$